



20V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D T _C = +25°C
-20V	$2.5 \text{m}\Omega$ @ $V_{GS} = -10V$	-60A
-20V	$3.5 \text{m}\Omega$ @ $V_{GS} = -4.5 \text{V}$	-60A

Description

This new generation P-Channel Enhancement Mode MOSFET is designed to minimize $R_{\text{DS}(\text{ON})}$ and yet maintain superior switching performance.

Applications

- Load Switch
- Notebook Battery Power Management

Features

- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

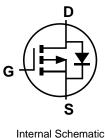
Mechanical Data

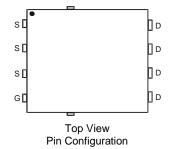
- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208@3
- Weight: 0.097 grams (Approximate)

POWERDI5060-8









Ordering Information (Note 4)

Part Number	Case	Packaging
DMP22M2UPS-13	POWERDI5060-8	2,500 / Tape & Reel

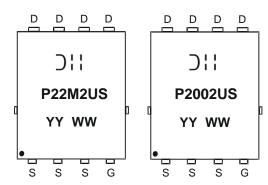
Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Bottom View

Marking Information

POWERDI5060-8



D: I = Manufacturer's Marking
P22M2US or P2002US = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Digit of Year (ex: 14 = 2014)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage	V _{GSS}	±12	V		
Continuous Prain Correct V 40V/Note 5	Steady State (Note 6)	$T_C = +25$ °C $T_C = +70$ °C		-60 -60	А
Continuous Drain Current, V _{GS} = 10V (Note 5)	t<10s	$T_A = +25$ °C $T_A = +70$ °C	l _D	-42 -33.5	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-100	Α		
Continuous Body Diode Forward Current (Note 5)	T _C = +25°C	- Is	-60	А	
Continuous Body Blode Forward Current (Note o)	t<10s	$T_A = +25$ °C	15	-5.6	Α
Avalanche Current, L = 0.1mH	I _{AS}	-37	А		
Avalanche Energy, L = 0.1mH	E _{AS}	69.8	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Units	
Total Davier Dissination (Note 5)	Steady State	-	2.3	W
Total Power Dissipation (Note 5)	t<10s	P_{D}	6.25	
Thermal Decistores Junction to Ambient (Note 5)	Steady State		55	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ hetaJA}$	20	
Total Power Dissipation (Note 5)	Steady State	P _D	104	W
Thermal Resistance, Junction to Case (Note 5)		R _{eJC}	0.9	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Note:

^{5.} Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

Package limited.

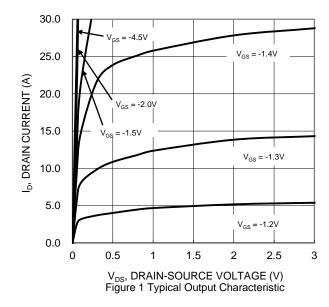


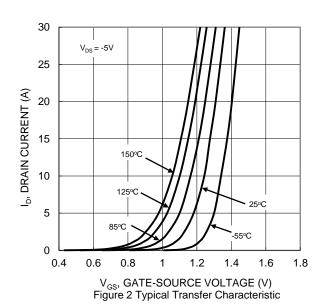
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-10	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-0.5	1	-1.4	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		_	_	2.5		$V_{GS} = -10V, I_D = -25A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	_	3.5	mΩ	$V_{GS} = -4.5V$, $I_{D} = -20A$	
		_	_	5.0		$V_{GS} = -2.5V, I_D = -15A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	12826	_			
Output Capacitance	Coss	_	2547	_	pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	1924	_		1 - 1101112	
Gate Resistance	R_G	_	4.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	_	476	_		V _{DS} = -10V, I _D = -20A	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	228	_	nC		
Gate-Source Charge	Q_{gs}	_	24.8	_	nc		
Gate-Drain Charge	Q _{gd}	_	61.9	_			
Turn-On Delay Time	t _{D(ON)}	_	14.2	_			
Turn-On Rise Time	t _R	_	35.4	_	20	$V_{DD} = -10V, V_{GEN} = -4.5V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	361	_	ns	$R_{GEN} = 1\Omega$, $I_D = -10A$	
Turn-Off Fall Time	t _F	_	224	_			
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	V_{SD}	_	-0.58	_	V	$V_{GS} = 0V, I_{S} = -5A$	
Reverse Recovery Time (Note 8)	t _{RR}	_	137	_	ns		
Reverse Recovery Charge (Note 8)	Q _{rr}	_	221	_	nC	1 400 di/dt 4000/	
Reverse Recovery Fall Time (Note 8)	ta	_	39	_	20	I _F = -10A, di/dt = 100A/µs	
Reverse Recovery Raise Time (Note 8)	t _b	_	98	_	ns		

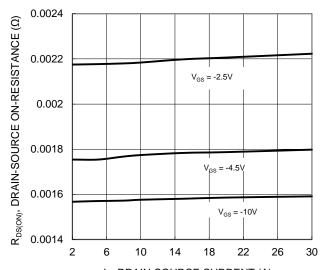
Notes: 7. Short duration pulse test used to minimize self-heating effect.



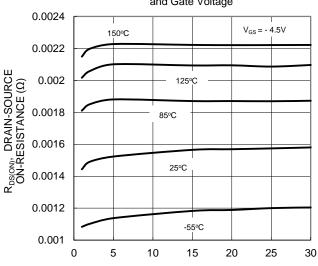








I_D, DRAIN-SOURCE CURRENT (A) Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage



 ${\rm I_D},\,{\rm DRAIN\,\,CURRENT(A)}$ Figure 5 Typical On-Resistance vs. Drain Current and Temperature

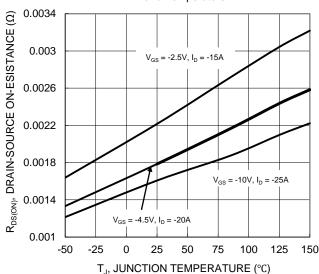
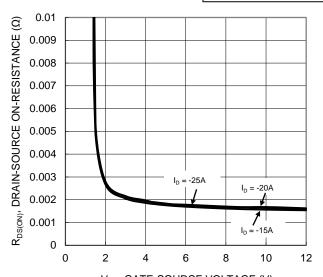
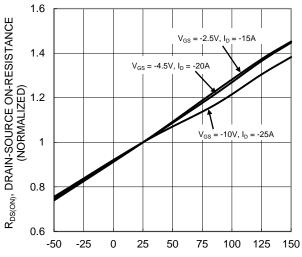


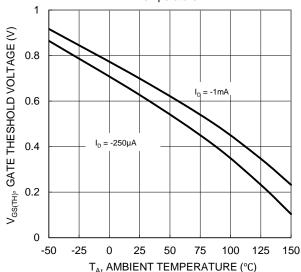
Figure 7 On-Resistance Variation with Temperature



 V_{GS} , GATE-SOURCE VOLTAGE (V) Figure 4 Typical Transfer Characteristic



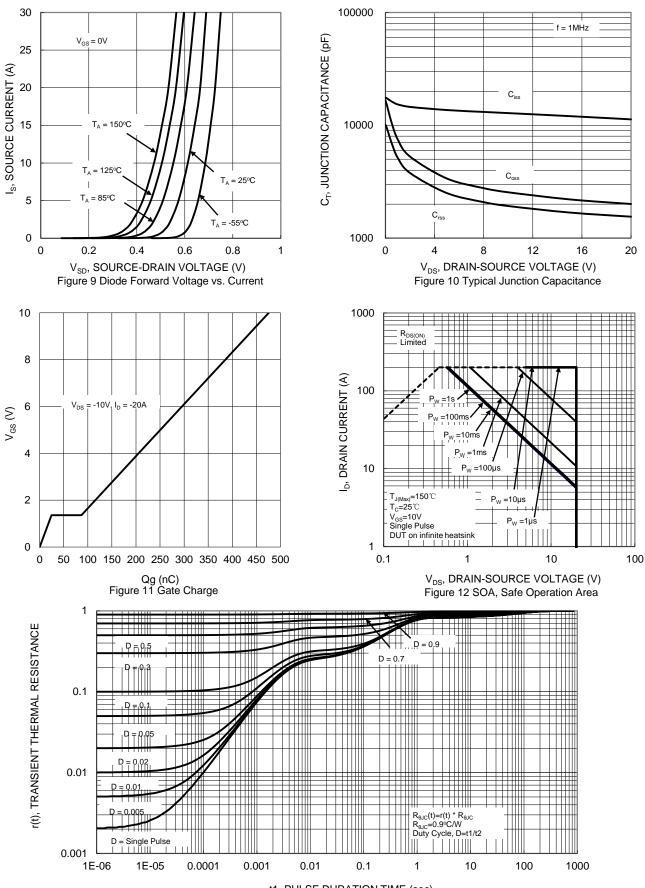
T_J, JUNCTION TEMPERATURE (°C) Figure 6 On-Resistance Variation with Temperature



 $\rm T_A, \, AMBIENT \, TEMPERATURE \, (^{\circ}C)$ Figure 8 Gate Theshold Variation vs Ambient Temperature





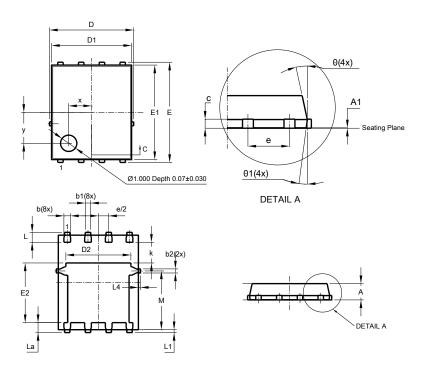


t1, PULSE DURATION TIME (sec)
Figure 13 Transient Thermal Resistance



Package Outline Dimensions

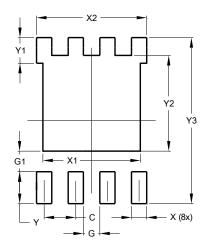
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



PowerDI5060-8						
(Type K)						
Dim	Min	Max	Тур			
Α	0.90 1.10		1.00			
A1	0	0.05	0.02			
b	0.33	0.51	0.41			
b1	0.300	0.366	0.333			
b2	0.20	0.35	0.25			
С	0.23	0.33	0.277			
D	5	.15 BS0	2			
D1	4.85	4.95	4.90			
D2	-	-	3.98			
Е	6	.15 BS0	3			
E1	5.75	5.85	5.80			
E2	3.56	3.76	3.66			
Е	1	.27BSC)			
k	-	-	1.27			
L	0.51	0.71	0.61			
La	0.51	0.71	0.61			
L1	0.05	0.20	0.175			
L4	-	-	0.125			
М	1 3.50 3.7		3.605			
Х			1.400			
у			1.900			
θ			11°			
θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated:

DMP22M2UPS-13